



3.1A 27V Synchronous Buck Converter

Description

The HF6230 is a monolithic synchronous buck regulator. The device integrates 90 mΩ MOSFETS that provide 3.1A continuous load current over a wide operating input voltage of 4.5V to 27V. Current mode control provides fast transient response and cycle- by-cycle current limit. An adjustable soft-start prevents inrush current at turn on.

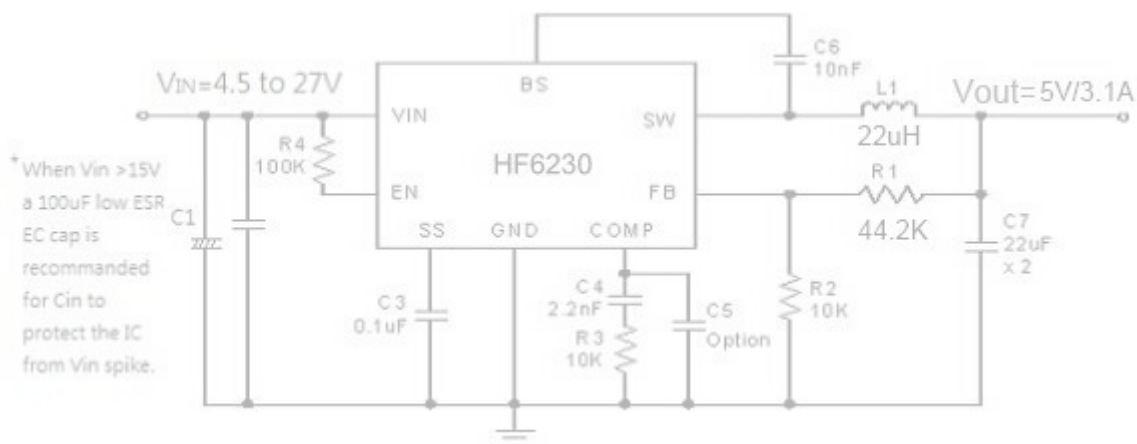
Features

- 3.1A Output Current
- Wide 4.5V to 27V Operating Input Range
- Fixed 340KHZ Frequency
- Integrated Power MOSFET switches
- Output Adjustable from 0.925V to 0.8Vin Up to 93% Efficiency
- Programmable Soft-Start
- Stable with Low ESR Ceramic Output Capacitors
- Cycle by Cycle Over Current Protection
- Short Circuit Protection
- Input Under Voltage Lockout
- Package : ESOP-8L

Applications

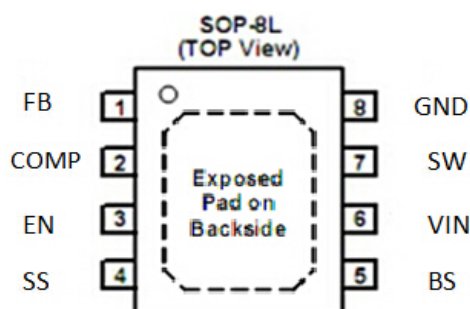
- Distributed Power Systems
- Networking Systems
- FPGA, DSP, ASIC Power Supplies
- Green Electronics/ Appliances
- Notebook Computers

Typical Application Circuit





Pin Assignments

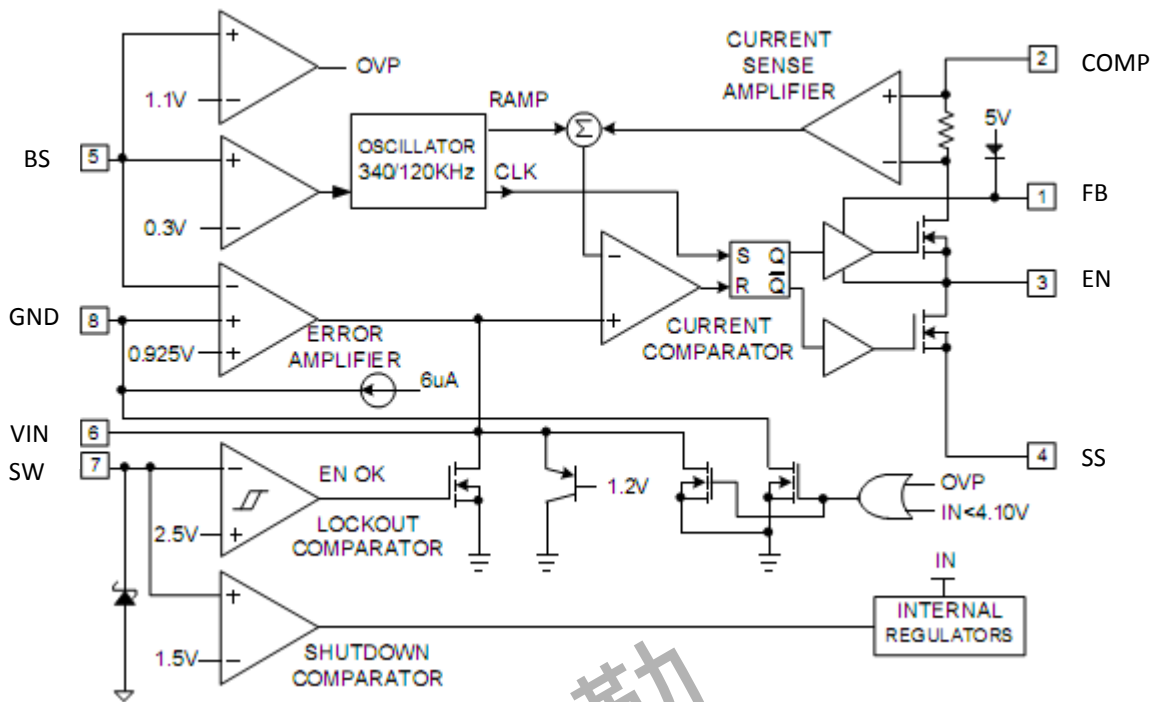


Pin Descriptions

Pin Number	Name	Description
1	FB	Feedback Input. The voltage at this pin is regulated to 0.925V. Connect to the resistor divider between output and ground to set output voltage.
2	COMP	Compensation Pin. See Stability Compensation in the Application Information section.
3	EN	Enable Input. When higher than 2.7V, this pin turns the IC on. When lower than 1.1V, this pin turns the IC off. Output voltage is discharged when the IC is off. This pin should not be left open. Recommend to put a 100K Ω pull up resistor to Vin for startup.
4	SS	Soft-Start Control Input. SS controls the soft-start period. Connect a capacitor from SS to GND to set the soft-start period. A 0.1 μ F capacitor sets the soft-start period to 15ms. To disable the soft-start feature, leave SS unconnected.
5	BS	Bootstrap. This pin acts as the positive rail for the high-side switch's gate driver. Connect a 0.01 μ F capacitor between BS and SW.
6	VIN	Input Supply. Bypass this pin to GND with a low ESR capacitor. See Input Capacitor in the Application Information section.
7	SW	Switch Output. Connect this pin to the switching end of the inductor.
8	GND	Ground.



Block Diagram



Absolute Maximum Ratings

Parameter	Value	Unit
Input Supply Voltage	-0.3 to 30	V
SW Voltage	-0.3 to VIN + 0.3	V
BS Voltage	VSW – 0.3 to VSW + 6	V
EN, FB, COMP Voltage	-0.3 to 5	V
Continuous SW Current	Internally limited	A
Junction to Ambient Thermal Resistance (θJA) (Test on Approximately 3 in ² Copper Area 1oz copper FR4 board)	20	°C/W
Junction to Ambient Case Resistance (θJC)	10	°C/W
SOP-8L Power Dissipation	Internally limited	W
Maximum Junction Temperature	150	°C
Storage Temperature Range	-65 to 150	°C
Moisture Sensitivity (MSL)	Please refer the MSL label on the IC package	

(Note: Exceeding these limits may damage the device. Even the duration of exceeding is very short.)



Exposure to absolute maximum rating conditions for long periods may affect device reliability.)

Recommended Operating Conditions

Parameter	Min	Max	Unit
Input Supply Voltage	4.5	27 ⁽¹⁾	V
Operating Junction Temperature	-20	+125 ⁽²⁾	°C

(Note (1): Operating the IC over this voltage is very easy to cause over voltage condition to VIN pin, SW pin, BS pin & EN pin)

(Note (2): If the IC experienced OTP, then the temperature may need to drop to <125 degree C to let the IC recover.)

Electrical Characteristics

(VIN = 12V, TA= 25°C unless otherwise specified.)

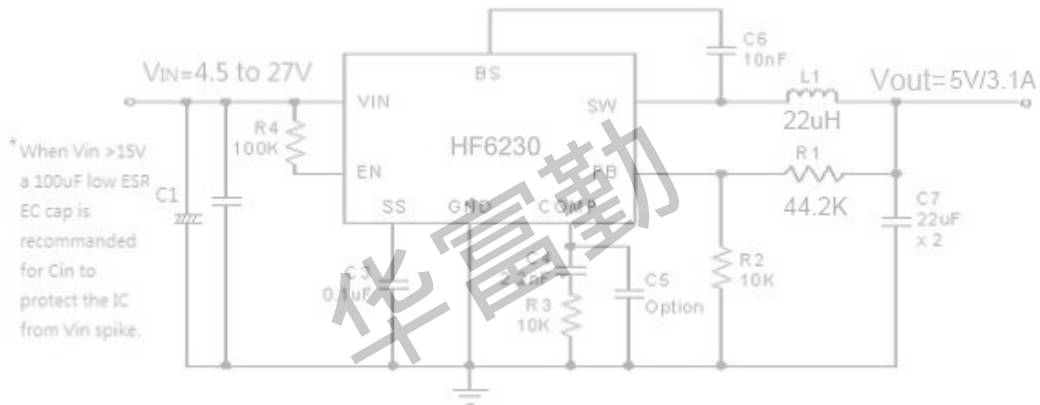
Parameter	Symbol	Test Conditions	Min	Typ	Max	Unit
Feedback Voltage	V _{FB}	4.5V ≤ VIN ≤ 27V	0.900	0.925	0.950	V
Feedback Overvoltage Threshold				1.1		V
High-Side Switch-On Resistance*				90		mΩ
Low-Side Switch-On Resistance*				70		mΩ
High-Side Switch Leakage		V _{EN} = 0V, V _{SW} = 0V		0.1	10	uA
Upper Switch Current Limit*		Minimum Duty Cycle	3.8	4.5		A
Lower Switch Current Limit*		From Drain to Source		1.2		A
COMP to Current Sense Limit Transconductance	G _{CS}			5.2		A/V
Error Amplifier Transconductance	G _{EA}	Ä _{ICOMP} = ±10uA		900		uA/V
Error Amplifier DC Gain*	A _{VEA}			400		V/V
Switching Frequency	f _{SW}		300	340	380	KHz
Short Circuit Switching Frequency		V _{FB} = 0		100		KHz
Minimum Duty Cycle*	D _{min}		7.5			%
Maximum Duty Cycle	D _{max}			92		%
EN Shutdown Threshold Voltage		V _{EN} Rising	1.1	1.4	2	V
EN Shutdown Threshold Voltage Hysteresis				180		mV
EN Lockout Threshold Voltage			2.2	2.5	2.7	V
EN Lockout Hysteresis				150		mV



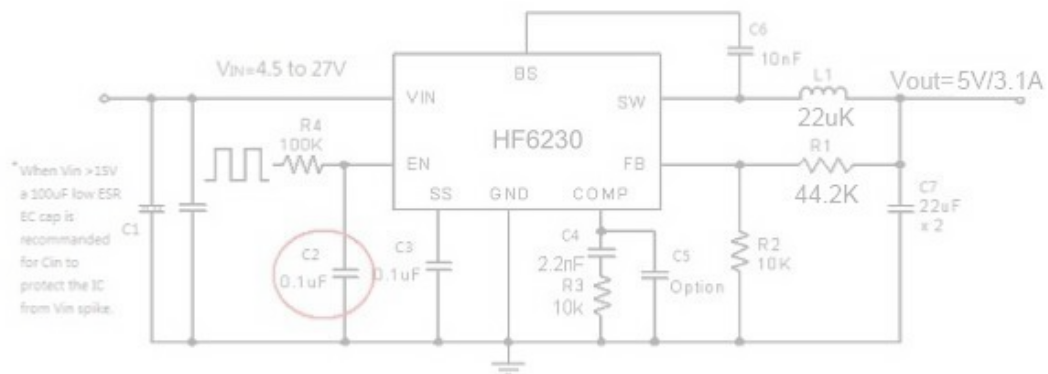
Supply Current in Shutdown		$V_{EN} = 0$		0.3	3.0	μA
IC Supply Current in Operation		$V_{EN} = 3\text{V}, V_{FB} = 1.0\text{V}$		1.3	1.5	mA
Input UVLO Threshold Rising	UVLO	V_{EN} Rising	3.80	4.0	4.40	V
Input UVLO Threshold Hysteresis				150		mV
Soft-start Current		$V_{SS} = 0\text{V}$		6		μA
Soft-start Period		$C_{SS} = 0.1\mu\text{F}$		13		mS
Thermal Shutdown Temperature*		Hysteresis = 25°C		155		$^\circ\text{C}$

Note: * Guaranteed by design, not tested

Application Description



HF6230 application circuit, 5V/3.1A output



HF6230 application circuit, 5V/3.1A output with EN function

Note: C2 is required for separate EN signal.



Output Voltage Setting

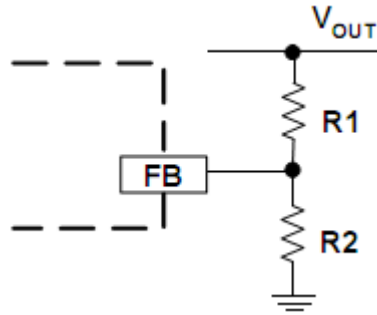


Figure1. Output Voltage Setting

Figure 1 shows the connections for setting the output voltage. Select the proper ratio of the two feedback resistors R1 and R2 based on the output voltage. Typically, use $R2 \approx 10\text{K}\Omega$ and determine R1 from the following equation:

$$R1 = R2 \left(\frac{V_{OUT}}{0.925V} - 1 \right) \quad (1)$$

Table1— Recommended Resistance Values

VOUT	R1	R2
1.0V	1.0 K Ω	12 K Ω
1.2V	3.0 K Ω	10 K Ω
1.8V	9.53 K Ω	10 K Ω
2.5V	16.9 K Ω	10 K Ω
3.3V	26.1 K Ω	10 K Ω
5V	44.2 K Ω	10 K Ω
12V	121 K Ω	10 K Ω

Inductor Selection

The inductor maintains a continuous current to the output load. This inductor current has a ripple that is dependent on the inductance value: higher inductance reduces the peak-to-peak ripple current. The tradeoff for high inductance value is the increase in inductor core size and series resistance, and the reduction in current handling capability. In general, select an inductance value L based on the ripple current requirement:

$$L = \frac{V_{OUT} \cdot (V_{IN} - V_{OUT})}{V_{IN} f_{SW} I_{OUTMAX} K_{RIPPLE}} \quad (2)$$

Where V_{IN} is the input voltage, V_{OUT} is the output voltage, f_{SW} is the switching frequency, and I_{OUTMAX} is the maximum output current, and K_{RIPPLE} is the ripple factor. Typically, choose $K_{RIPPLE} = \sim 30\%$ to correspond to the peak-to-peak ripple current being $\sim 30\%$ of the maximum output current.

With this inductor value, the peak inductor current is $I_{OUT} \cdot (1 + K_{RIPPLE} / 2)$. Make sure that this peak inductor current is less than the upper switch current limit. Finally, select the inductor core size so that it



does not saturate at the current limit. Typical inductor values for various output voltages are shown in Table 2.

VOUT	1.0V	1.2V	1.5V	1.8V	2.5V	3.3V	5V	9V
L	4.7uH	4.7uH	10uH	10uH	10uH	10uH	10uH	22uH

Table2. Typical Inductor Values

Input Capacitor

The input capacitor needs to be carefully selected to maintain sufficiently low ripple at the supply input of the converter. A low ESR Electrolytic (EC) capacitor is highly recommended. Since large current flows in and out of this capacitor during switching, its ESR also affects efficiency.

When EC cap is used, the input capacitance needs to be equal to or higher than 100uF. The RMS ripple current rating needs to be higher than 50% of the output current. The input capacitor should be placed close to the VIN and GND pins of the IC, with the shortest traces possible. The input capacitor can be placed a little bit away if a small parallel 0.1uF ceramic capacitor is placed right next to the IC.

When V_{IN} is $>15V$, pure ceramic C_{in} (* no EC cap) is not recommended. This is because the ESR of a ceramic cap is often too small, pure ceramic C_{in} will work with the parasite inductance of the input trace and forms a V_{IN} resonant tank. When V_{IN} is hot plug in/out, this resonant tank will boost the V_{in} spike to a very high voltage and damage the IC.

Output Capacitor

The output capacitor also needs to have low ESR to keep low output voltage ripple. In the case of ceramic output capacitors, RESR is very small and does not contribute to the ripple. Therefore, a lower capacitance value can be used for ceramic capacitors. In the case of tantalum or electrolytic capacitors, the ripple is dominated by RESR multiplied by the ripple current. In that case, the output capacitor is chosen to have sufficiently low ESR.

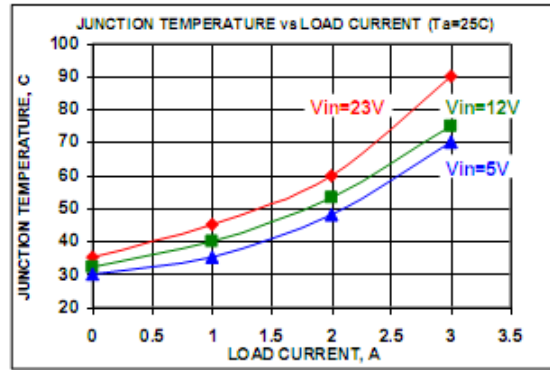
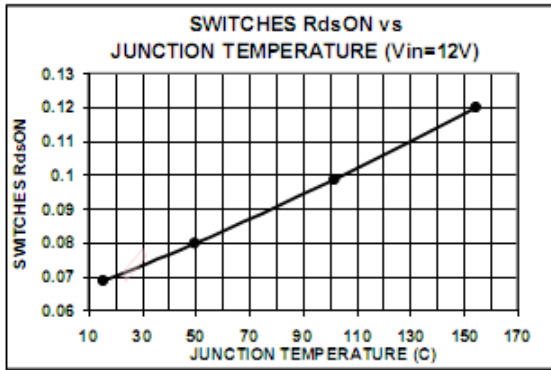
For ceramic output capacitors, typically choose two capacitors of about 22uF. For tantalum or electrolytic capacitors, choose a capacitor with less than 50mΩ ESR.

Optional Schottky Diode

During the transition between high-side switch and low-side switch, the body diode of the low side power MOSFET conducts the inductor current. The forward voltage of this body diode is high. An optional Schottky diode may be paralleled between the SW pin and GND pin to improve overall efficiency. Table 3 lists example Schottky diodes and their Manufacturers.

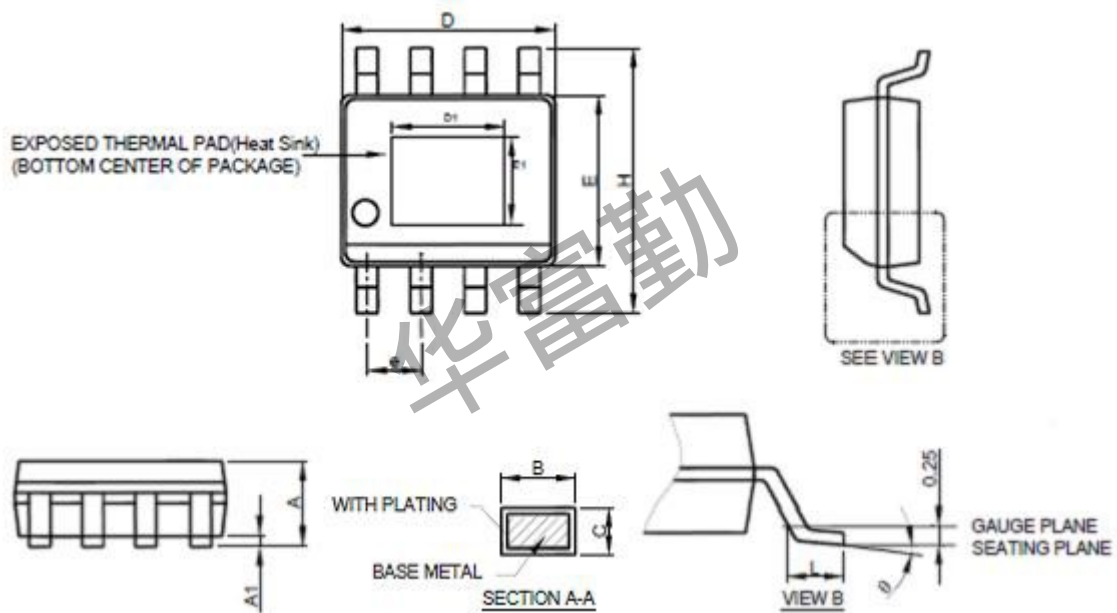
Table 3 – Diode Selection Guide

Vin max	Part Number	Voltage/Current Rating	Vendor
<20V	B130	30V, 1A	Lite-on semiconductor corp.
<20V	SK13	30V, 1A	Lite-on semiconductor corp.
>20V	B140	40V, 1A	Lite-on semiconductor corp.
>20V	SK14	40V, 1A	Lite-on semiconductor corp.



Package Information(All Dimensions in mm)

ESOP-8L

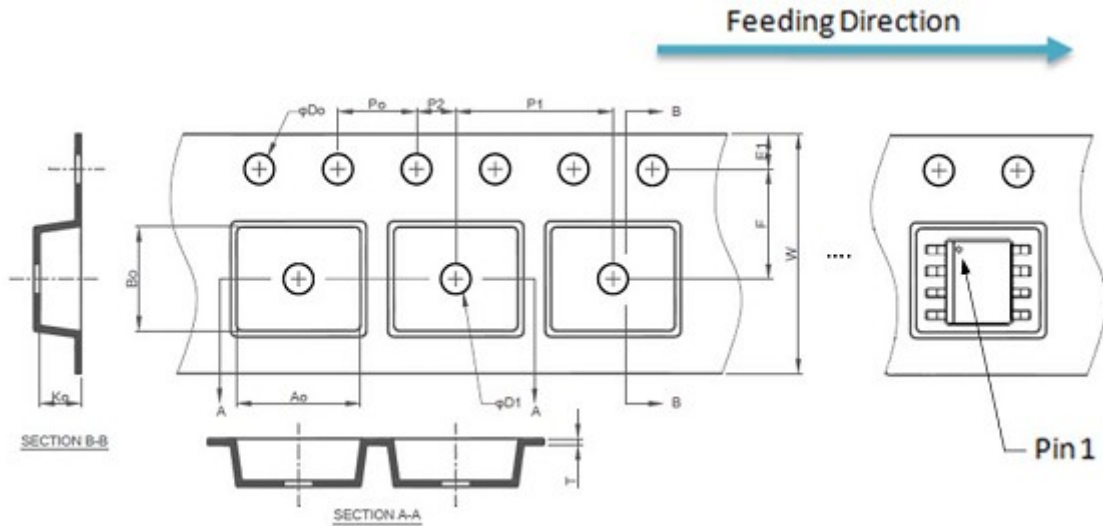


Symbol	Dimensions In Millimeters	
	Min	Max
A	1.35	1.75
A1	0.05	0.25
B	0.31	0.51
C	0.17	0.25
D	4.70	5.10
E	3.70	4.10
e	1.27BSC	
H	5.80	6.20



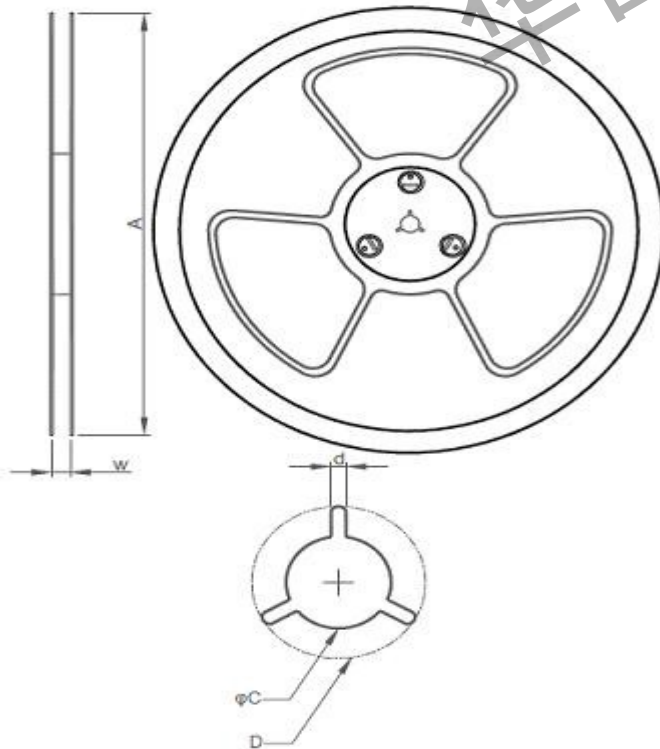
L	0.40	1.27
è	0°	8°
D1	3.10REF	
E1	2.21REF	

Tape/Reel



- Note: 1. Refer to EIA-481-B
 2. 10 sprocket hole pitch cumulative tolerance ± 0.2
 3. Material: conductive polystyrene
 4. Ao and Bo measured on a plane 0.3mm above the bottom of the pocket
 5. Ko measured from a plane on the inside bottom of the pocket to the top surface of the carrier

SYMBOL	Ao	Bo	Ko	T	Do	D1
SPEC.	0.90±0.20	5.40±0.20	2.10±0.20	0.30±0.05	1.50 +0.10 -0.00	1.50 min.
SYMBOL	Po	P1	P2	E1	F	W
SPEC.	4.00±0.10	8.00±0.10	2.00±0.05	1.75±0.10	5.50±0.05	12.00±0.30



Package Type	A	W	C	d	D
TO-252-3L	330±2	16.4 +2.0 -0.0	13.0 +0.5 -0.2	1.5 MIN.	20.2 MIN.
SOP-8 SOT-223	330±2	12.4 +2.0 -0.0	13.0 +0.5 -0.2	1.5 MIN.	20.2 MIN.
SOT-89-3L	178±2	12.4 +2.0 -0.0	13.0 +0.5 -0.2	1.5 MIN.	20.2 MIN.

Note: Refer to EIA-481-B